

Date:- 12 Feb 2021

Data Sheet Issue: 2

High Power Sonic FRD Type E3000EC45E

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	4500	V
V _{RSM}	Non-repetitive peak reverse voltage, (note 1)	4600	V
V _{R(d.c.)}	Maximum reverse d.c. voltage (note 1)	2800	V

	OTHER RATINGS (note 6)	MAXIMUM LIMITS	UNITS
I _{F(AV)M}	Mean forward current, T _{sink} =55°C, (note 2)	3410	Α
I _{F(AV)M}	Mean forward current. T _{sink} =100°C, (note 2)	2070	Α
I _{F(AV)M}	Mean forward current. T _{sink} =100°C, (note 3)	1060	Α
I _{F(AV)M}	Mean forward current. T _{sink} =100°C, (note 4)	1418	Α
I _{F(RMS)}	Nominal RMS forward current, T _{sink} =25°C, (note 2)	6475	Α
I _{F(d.c.)}	D.C. forward current, T _{sink} =25°C, (note 5)	5680	Α
I _{FSM}	Peak non-repetitive surge t _p =10ms, V _{RM} =60%V _{RRM} , (note 6)	45.7	kA
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _{RM} ≤10V, (note 6)	50.3	kA
l ² t	I ² t capacity for fusing t _p =10ms, V _{RM} =60%V _{RRM} , (note 6)	10.5×10 ⁶	A ² s
l ² t	I²t capacity for fusing t _p =10ms, V _{RM} ≤10V, (note 6)	12.7×10 ⁶	A ² s
Prr	Maximum non-repetitive peak reverse recovery power, (note 8)	14.2	MW
T _{j op}	Operating temperature range	-40 to +140	°C
T _{stg}	Storage temperature range	-40 to +150	°C

Notes:-

- 1) De-rating factor of 0.13% per °C is applicable for T_i below 25°C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Anode side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
- 5) Double side cooled.
- 6) Half-sinewave, 140°C T_i initial.
- 7) Current (I_F) ratings have been calculated using V_{T0} and r_T (see page 2)
- 8) T_j=T_{jop}, I_F=3000Å, di/dt=5000A/µs V_r=2800V and L_s=120nH. Test circuit and sample waveform are shown in diagram 1. IGBT type T2960BB45E used as switch.



Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	2.88	3.10	I _{FM} =3000A	V
		-	-	4.27	I _{FM} =6000A	
V _{T0}	Threshold voltage	-	-	2.124	Current range 3410A - 10230A (Note 2)	V
r⊤	Slope resistance	-	-	0.339	Current range 34 TOA - 10230A (Note 2)	mΩ
V _{T01}	Threshold voltage	-	-	2.036	Current range 3000A - 9000A	
r _{T1}	Slope resistance	-	-	0.355		
V_{FRM}	Maximum forward recovery voltage	-	-	205	di/dt = 5000A/µs	٧
		-	-	100	di/dt = 5000A/µs, T _j =25°C	
	Peak reverse current	-	-	120	Rated V _{RRM}	mA
IRRM		-	-	2	Rated V _{RRM} , T _j =25°C	
Qrr	Recovered charge	-	5000	5530		μC
Qra	Recovered charge, 50% Chord	-	1900	-		μC
I _{rm}	Reverse recovery current	-	3050	3500	I _{FM} =3000A, t _p =40μs, di/dt=5000A/μs, V _r =2800V, 50% Chord (note 3)	Α
t _{rr}	Reverse recovery time, 50% Chord	-	1.25	-	VI-2000 V, 00 / 0 Uniona (Note 6)	μs
Err	Reverse recovery energy loss	-	9.5	10.5		J
		-	-	0.005	Double side cooled	K/W
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.0125	Anode side cooled	K/W
				0.0085	Cathode side cooled	
F	Mounting force	75	-	85	(Note 4)	kN
Wt	Weight	-	1.58	-		kg

Notes:-

- 1) Unless otherwise indicated T_i=140°C.
- 2) V_{T0} and r_T were used to calculate the current ratings illustrated on page one.
 3) Figures 3-7 were compiled using these conditions. Test circuit and sample waveform are shown in diagram 1.
- 4) For clamp forces outside these limits, please consult factory.



Additional information on Ratings and Characteristics

1.0 De-rating Factor

A blocking voltage de-rating factor of 0.13% per °C is applicable to this device for T_i below 25°C.

2.0 ABCD Constants

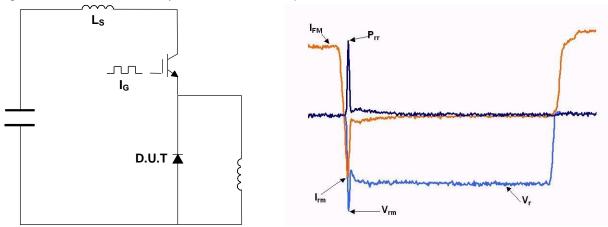
These constants (applicable only over current range of V_F characteristic in Figure 1) are the coefficients of the expression for the forward characteristic given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

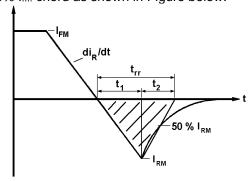
where I_F = instantaneous forward current.

3.0 Reverse recovery ratings

Diagram 1 - Reverse Recovery test circuit and sample waveform



(i) Q_{ra} is based on 50% I_{rm} chord as shown in Figure below.



(ii) Q_{rr} is based on a 15 μs integration time.

$$Q_{rr} = \int_{0}^{15us} i_{rr} \cdot \mathrm{d}t$$

l.e.



(iii)
$$K \ Factor = \frac{t_1}{t_2}$$

4.0 Reverse Recovery Loss

The following procedure is recommended for use where it is necessary to include reverse recovery loss.

From waveforms of recovery current obtained from a high frequency shunt (see Note 1) and reverse voltage present during recovery, an instantaneous reverse recovery loss waveform must be constructed. Let the area under this waveform be E joules per pulse. A new sink temperature can then be evaluated from:

$$T_{SINK} = T_{J(MAX)} - E \cdot \left[k + f \cdot R_{th(J-Hs)}\right]$$

Where $k = 0.2314 \, (^{\circ}C/W)/s$

E = Area under reverse loss waveform per pulse in joules (W.s.)

f = Rated frequency in Hz at the original sink temperature.

 $R_{th(J-Hs)} = d.c.$ thermal resistance (°C/W)

The total dissipation is now given by:

$$W_{\scriptscriptstyle (tot)} = W_{\scriptscriptstyle (original)} + E \cdot f$$

NOTE 1 - Reverse Recovery Loss by Measurement

This device has a low reverse recovered charge and peak reverse recovery current. When measuring the charge, care must be taken to ensure that:

- (a) AC coupled devices such as current transformers are not affected by prior passage of high amplitude forward current.
- (b) A suitable, polarised, clipping circuit must be connected to the input of the measuring oscilloscope to avoid overloading the internal amplifiers by the relatively high amplitude forward current signal.
- (c) Measurement of reverse recovery waveform should be carried out with an appropriate critically damped snubber, connected across diode anode to cathode. The formula used for the calculation of this snubber is shown below:

$$R^2 = 4 \cdot \frac{V_r}{C_s \cdot di/dt}$$

Where: V_r = Commutating source voltage

Cs = Snubber capacitance R = Snubber resistance

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations



$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^{2} + 4 \cdot ff^{2} \cdot r_{T} \cdot W_{AV}}}{2 \cdot ff^{2} \cdot r_{T}}$$

Where V_{T0} =2.124V, r_T =0.339m Ω

ff = form factor (normally unity for fast diode applications)

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j(MAX)} - T_K$$

5.2 Calculation of V_F using ABCD Coefficients

The forward characteristic I_F Vs V_F, on page 6 is represented in two ways;

- (i) the well-established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, and D forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given in this report for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	140°C Coefficients
Α	0.0670623	0.5420526
В	0.2532695	0.02967722
С	0.2691468×10 ⁻³	0.1043956×10 ⁻³
D	0.134857×10 ⁻³	0.03664546

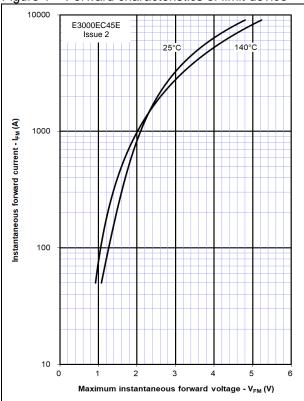
25°C

10000



Curves

Figure 1 – Forward characteristics of limit device



Maximum forward recovery voltage - VFRM (V) 140°C

Figure 2 - Maximum forward recovery voltage

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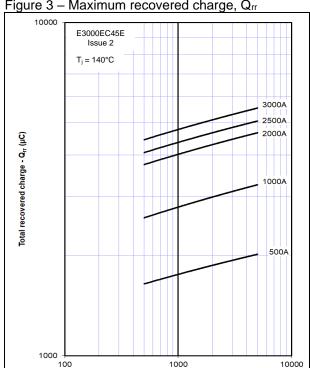
100

10 100

Figure 4 – Maximum recovery charge, Qra (50% chord)

1000

Rate of rise of forward current - di/dt (A/µs)



Commutation rate - di/dt (A/µs)

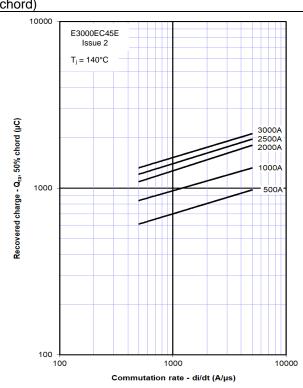


Figure 3 - Maximum recovered charge, Q_{rr}



Figure 5 - Maximum reverse current, Irm

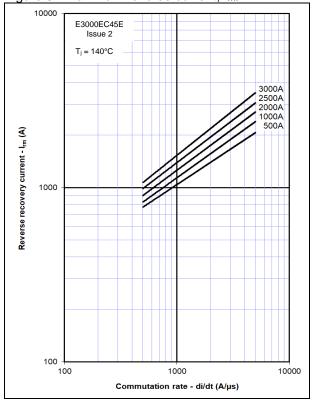


Figure 6 – Maximum recovery time, t_{rr} (50% chord)

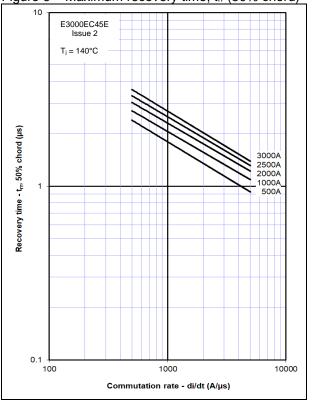


Figure 7 – Typical reverse recovery energy per

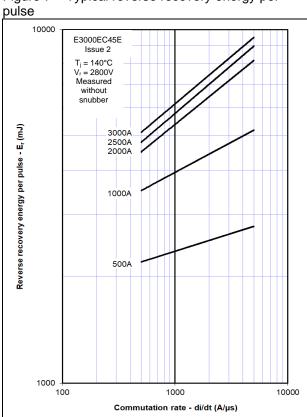


Figure 8 – Sine wave energy per pulse

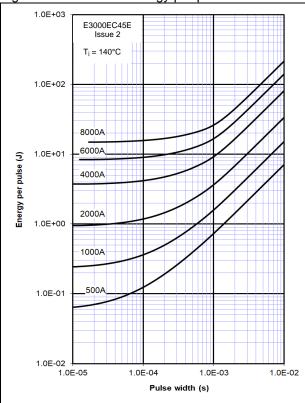




Figure 9 - Sine wave frequency vs. pulse width

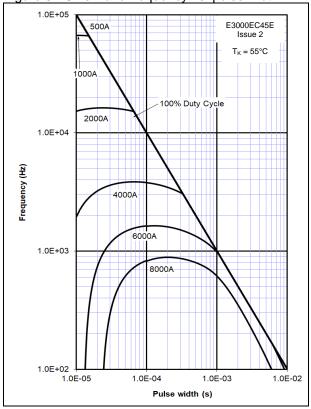


Figure 10 – Sine wave frequency vs. pulse width

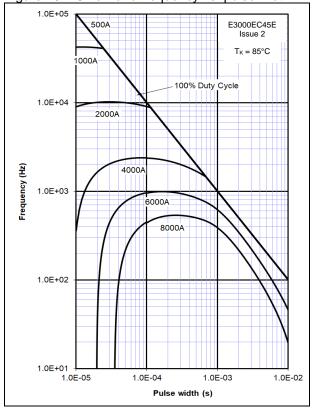


Figure 11 - Square wave energy per pulse

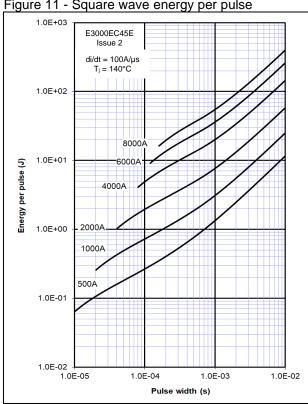


Figure 12 - Square wave energy per pulse

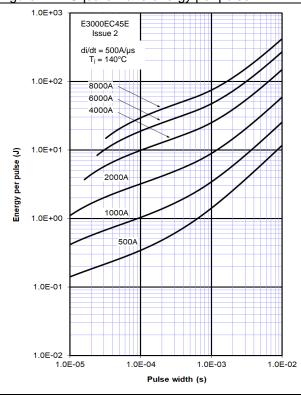




Figure 13 - Square wave frequency vs pulse width

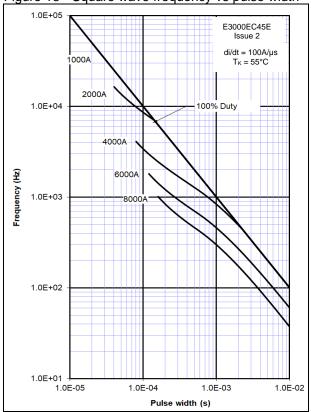


Figure 14 - Square wave frequency vs pulse width

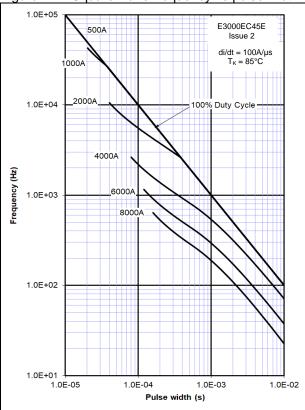


Figure 15 - Square wave frequency vs pulse width

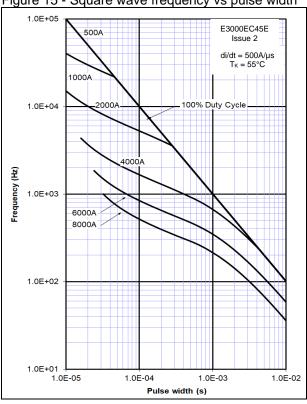


Figure 16 - Square wave frequency vs pulse width

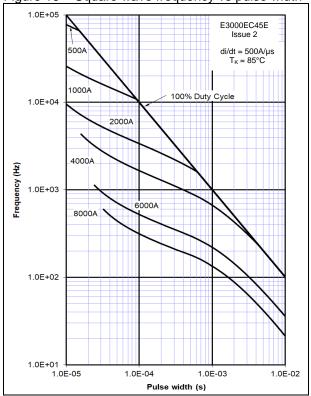




Figure 17 - Safe operating area

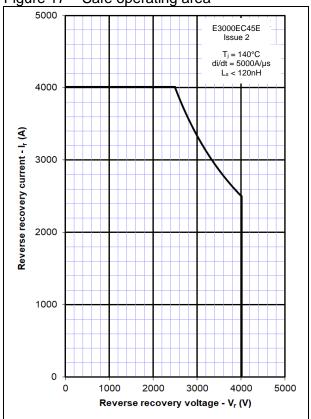


Figure 18 – Transient thermal impedance

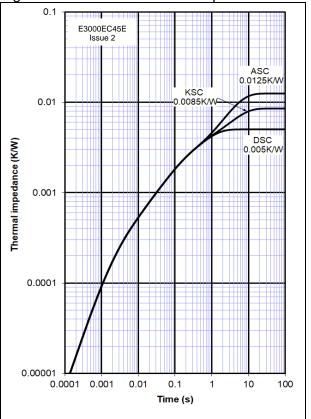
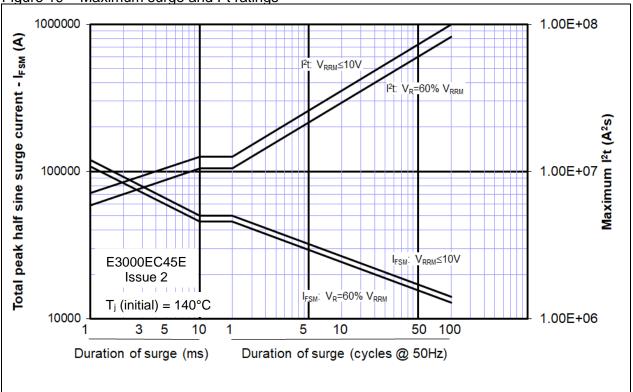
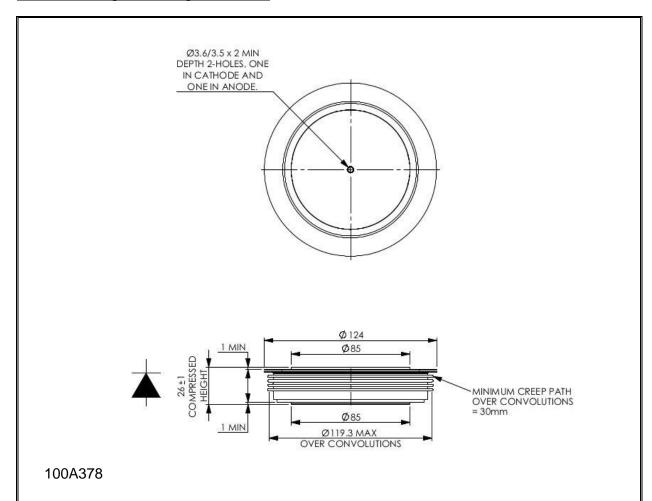


Figure 19 - Maximum surge and I2t ratings





Outline Drawing & Ordering Information



ORDERI	NG INFORMATION	(Please quote 10 digit code as below)		
E3000	EC	45	E	
Fixed Type Code	Fixed outline code	Fixed voltage code V _{RRM} /100 45	Fixed code, product series	

Order code: E3000EC45E - 4500V V_{RRM} , 26mm clamp height capsule.

IXYS UK Westcode Ltd

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